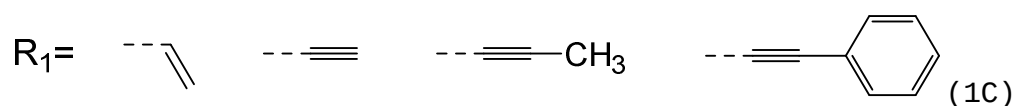
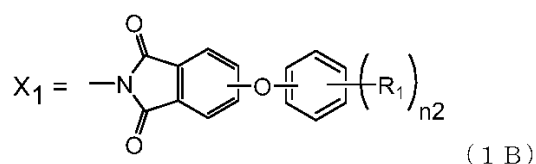
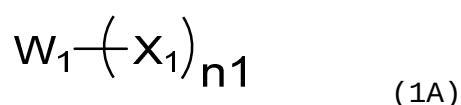


TITLE OF INVENTION: MATERIAL FOR FORMING ORGANIC FILM, SUBSTRATE FOR MANUFACTURING SEMICONDUCTOR DEVICE, METHOD FOR FORMING ORGANIC FILM, PATTERNING PROCESS, COMPOUND FOR FORMING ORGANIC FILM, AND AROMATIC CARBOXYLIC ANHYDRIDE

ABSTRACT

An organic film, containing: (A) a compound represented by the formula (1A); and (B) an organic solvent, where W1 represents an n1-valent organic group, "n1" represents an integer of 2 to 4, X1 represents a group represented by the following general formula (1B), "n2" represents 1 or 2, and R1 represents any of groups represented by the following formulae (1C). A compound that cures in an inert gas and in air, and forms an organic film with excellent heat resistance and properties of filling and planarizing, has favorable film-formability on and adhesiveness; a material for forming an organic film, containing the compound; a substrate for manufacturing a semiconductor device; a method for forming an organic film, using the material.



[Fig.1]